

8-BIT SHIFT REGISTERS WITH 3-STATE OUTPUT REGISTERS

Check for Samples: SN54HC595 SN74HC595

FEATURES

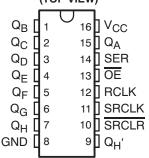
- · 8-Bit Serial-In, Parallel-Out Shift
- . Wide Operating Voltage Range of 2 V to 6 V
- High-Current 3-State Outputs Can Drive Up To 15 LSTTL Loads
- Low Power Consumption: 80-μA (Max) I_{CC}
- $t_{pd} = 13 \text{ ns (Typ)}$
- ±6-mA Output Drive at 5 V
- Low Input Current: 1 μA (Max)
- Shift Register Has Direct Clear

DESCRIPTION

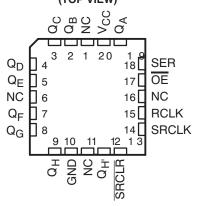
The 'HC595 devices contain an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage register. The shift register has a direct overriding clear (SRCLR) input, serial (SER) input, and serial outputs for cascading. When the output-enable (OE) input is high, the outputs are in the high-impedance state.

Both the shift register clock (SRCLK) and storage register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register.

SN54HC595...J OR W PACKAGE SN74HC595...D, DB, DW, N, NS, OR PW PACKAGE (TOP VIEW)



SN54HC595...FK PACKAGE (TOP VIEW)



NC - No internal connection

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION(1)

T _A	PA	CKAGE (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP - N	Tube of 25	SN74HC595N	SN74HC595N
		Tube of 40	SN74HC595D	
	SOIC - D	Reel of 2500	SN74HC595DR	HC595
		Reel of 250	SN74HC595DT	
–40°C to 85°C	SOIC - DW	Tube of 40	SN74HC595DW	HC595
-40°C 10 65°C	SOIC - DW	Reel of 2000	SN74HC595DWR	_ HC383
	SOP - NS	Reel of 2000	SN74HC595NSR	HC595
	SSOP - DB	Reel of 2000	SN74HC595DBR	HC595
	TCCOD DW	Tube of 90	SN74HC595PW	HC595
	TSSOP – PW	Reel of 2000	SN74HC595PWR	_ HC383
	CDIP - J	Tube of 25	SNJ54HC595J	SNJ54HC595J
–55°C to 125°C	CFP - W	Tube of 150	SNJ54HC595W	SNJ54HC595W
	LCCC - FK	Tube of 55	SNJ54HC595FK	SNJ54HC595FK

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

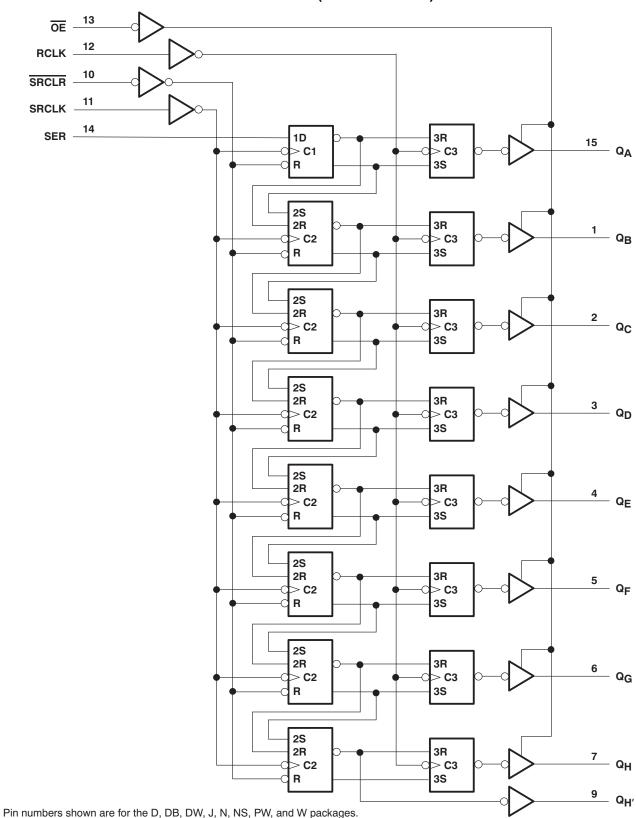
Table 1. FUNCTION TABLE

		INPUTS			FUNCTION
SER	SRCLK	SRCLR	RCLK	OE	FUNCTION
Х	Х	Х	Х	Н	Outputs Q _A -Q _H are disabled.
Χ	Χ	Χ	Χ	L	Outputs Q _A -Q _H are enabled.
Χ	X	L	Χ	Χ	Shift register is cleared.
L	↑	Н	Х	Х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.
Н	↑	Н	Х	Х	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.
Χ	Χ	Х	↑	Х	Shift-register data is stored in the storage register.

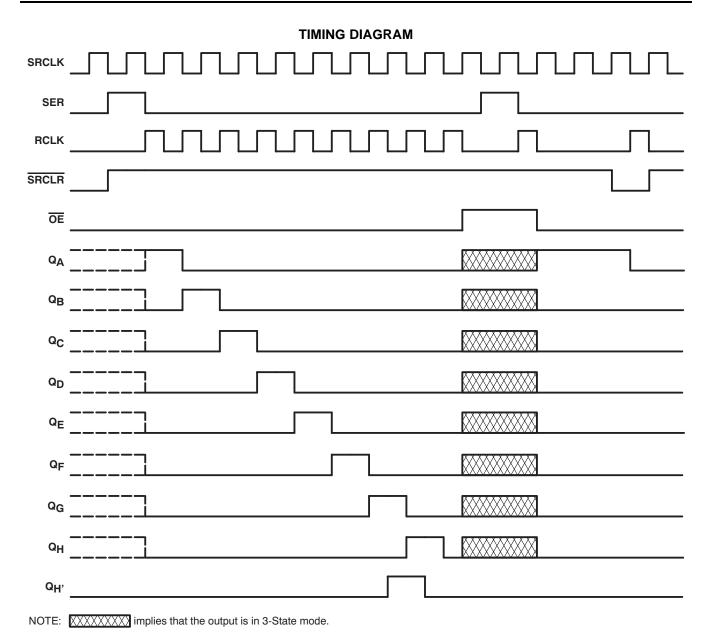
⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



LOGIC DIAGRAM (POSITIVE LOGIC)









ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

V_{CC}	Supply voltage range		-0.5 V to 7 V
I _{IK}	Input clamp current ⁽²⁾	$V_I < 0$ or $V_I > V_{CC}$	±20 mA
lok	Output clamp current (2)	$V_O < 0$ or $V_O > V_{CC}$	±20 mA
lo	Continuous output current	$V_{O} = 0$ to V_{CC}	±35 mA
	Continuous current through VCC or GND		±70 mA
		D package	73°C/W
		DB package	82°C/W
0	Dealers thermal impedance (3)	DW package	57°C/W
θ_{JA}	Package thermal impedance (3)	N package	67°C/W
		NS package	64°C/W
		PW package	108°C/W
T _{stg}	Storage temperature range		-65°C to 150°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS(1)

			SN	154HC59	5	SN	174HC59	5	
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
V_{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
		V _{CC} = 2 V			0.5			0.5	
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V			1.35			1.35	V
		V _{CC} = 6 V			1.8			1.8	
VI	Input voltage	·	0		V _{CC}	0		V _{CC}	V
Vo	Output voltage		0		V _{CC}	0		V _{CC}	V
		V _{CC} = 2 V			1000			1000	
Δt/Δν	Input transition rise/fall time (2)	V _{CC} = 4.5 V			500			500	ns
		$V_{CC} = 6 V$			400			400	
T _A	Operating free-air temperature		-55		125	-40		85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

⁽²⁾ If this device is used in the threshold region (from V_{IL}max = 0.5 V to V_{IH}min = 1.5 V), there is a potential to go into the wrong state from induced grounding, causing double clocking. Operating with the inputs at t_t = 1000 ns and V_{CC} = 2 V does not damage the device; however, functionally, the CLK inputs are not ensured while in the shift, count, or toggle operating modes.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		T CONDITIONS			_A = 25°C		SN54H	C595	SN74H	C595	LINUT
PARAMETER	IES	T CONDITIONS	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	1.998		1.9		1.9		
		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
			6 V	5.9	5.999		5.9		5.9		
V _{OH}	$V_I = V_{IH}$ or V_{IL}	$Q_{H'}$, $I_{OH} = -4 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		V
		$Q_A - Q_H$, $I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
		$Q_{H'}$, $I_{OH} = -5.2 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
		$Q_A - Q_H$, $I_{OH} = -7.8 \text{ mA}$		5.48	5.8		5.2		5.34		
			2 V		0.002	0.1		0.1		0.1	
		$I_{OL} = 20 \mu A$	4.5 V		0.001	0.1		0.1		0.1	
			6 V		0.001	0.1		0.1		0.1	
V _{OL}	$V_I = V_{IH}$ or V_{IL}	$Q_{H'}$, $I_{OL} = 4 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	V
		$Q_A - Q_H$, $I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
		$Q_{H'}$, $I_{OL} = 5.2 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
		$Q_A - Q_H$, $I_{OL} = 7.8 \text{ mA}$			0.15	0.26		0.4		0.33	
I _I	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
I _{OZ}	$V_O = V_{CC}$ or 0, 0	Q _A -Q _H	6 V		±0.01	±0.5		±10		±5	μΑ
I _{CC}	$V_I = V_{CC}$ or 0, I_O	= 0	6 V			8		160		80	μΑ
C _i			2 V to 6 V		3	10		10		10	pF



TIMING REQUIREMENTS

over operating free-air temperature range (unless otherwise noted)

			.,	$T_A = 2$	25°C	SN54H	C595	SN74H	C595	
			V _{CC}	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		6		4.2		5	
f _{clock}	Clock frequency		4.5 V		31		21		25	MHz
			6 V		36		25		29	
			2 V	80		120		100		
		SRCLK or RCLK high or low	4.5 V	16		24		20		
	Dulas duration		6 V	14		20		17		
t _w	Pulse duration		2 V	80		120		100		ns
		SRCLR low	4.5 V	16		24		20		
			6 V	14		20		17		
			2 V	100		150		125		
		SER before SRCLK↑	4.5 V	20		30		25		
			6 V	17		25		21		
			2 V	75		113		94		
		SRCLK↑ before RCLK↑ ⁽¹⁾	4.5 V	15		23		19		
	Catum times		6 V	13		19		16		
t _{su}	Setup time		2 V	50		75		65		ns
		SRCLR low before RCLK↑	4.5 V	10		15		13		
			6 V	9		13		11		
			2 V	50		75		60		
		SRCLR high (inactive) before SRCLK↑	4.5 V	10		15		12		
			6 V	9		13		11		
			2 V	0		0		0		
t _h	Hold time, SER	after SRCLK↑	4.5 V	0		0		0		ns
			6 V	0		0		0		

⁽¹⁾ This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_1 = 50 \text{ pF}$ (unless otherwise noted)

PARAMETER	FROM	то	V	T	_A = 25°C		SN54H	C595	SN74H	C595	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
			2 V	6	26		4.2		5		
f _{max}			4.5 V	31	38		21		25		MHz
			6 V	36	42		25		29		
			2 V		50	160		240		200	
	SRCLK	$Q_{H'}$	4.5 V		17	32		48		40	
			6 V		14	27		41		34	
t _{pd}			2 V		50	150		225		187	ns
	RCLK	Q _A -Q _H	4.5 V		17	30		45		37	
			6 V		14	26		38		32	
			2 V		51	175		261		219	
t _{PHL}	SRCLR	$Q_{H'}$	4.5 V		18	35		52		44	ns
			6 V		15	30		44		37	
			2 V		40	150		255		187	
t _{en}	ŌĒ	Q _A -Q _H	4.5 V		15	30		45		37	ns
			6 V		13	26		38		32	
			2 V		42	200		300		250	
t _{dis}	ŌĒ	Q _A -Q _H	4.5 V		23	40		60		50	ns
			6 V		20	34		51		43	
			2 V		28	60		90		75	
		Q _A -Q _H	4.5 V		8	12		18		15	
			6 V		6	10		15		13	
t _t			2 V		28	75		110		95	ns
		$Q_{H'}$	4.5 V		8	15		22		19	
			6 V		6	13		19		16	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted)

DADAMETED	FROM	то	v	T	λ = 25°C		SN54H	C595	SN74H	C595	LINUT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V		60	200		300		250	
t _{pd}	RCLK	$Q_A - Q_H$	4.5 V		22	40		60		50	ns
			6 V		19	34		51		43	
			2 V		70	200		298		250	
t _{en}	ŌĒ	Q_A – Q_H	4.5 V		23	40		60		50	ns
			6 V		19	34		51		43	
			2 V		45	210		315		265	
t _t		$Q_A - Q_H$	4.5 V		17	42		63		53	ns
			6 V		13	36		53		45	

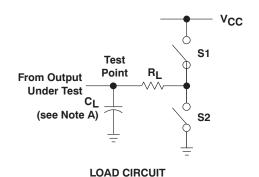
OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

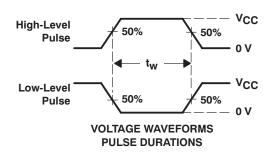
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load	400	pF

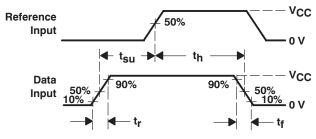


PARAMETER MEASUREMENT INFORMATION

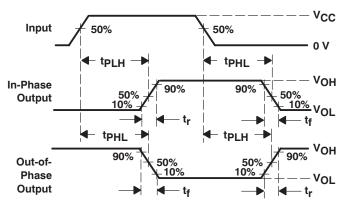


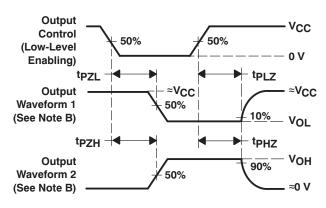
PARAI	METER	RL	CL	S1	S2
	^t PZH	1 k Ω	50 pF or	Open	Closed
ten	tPZL	1 K22	150 pF	Closed	Open
t	tPHZ	1 k Ω	50 pF	Open	Closed
^t dis	tPLZ	1 K22	30 pr	Closed	Open
t _{pd} or	t _{pd} or t _t		50 pF or 150 pF	Open	Open





VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f = 6 \ ns$, $t_f = 6 \ ns$.
- D. For clock inputs, f_{max} is measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time, with one input transition per measurement.
- F. tpLz and tpHz are the same as tdis.
- G. tpzL and tpzH are the same as ten.
- H. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

29-Aug-2012

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
5962-86816012A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	
5962-8681601EA	ACTIVE	CDIP	J	16	1	TBD	Call TI	Call TI	
5962-8681601VEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	
5962-8681601VFA	ACTIVE	CFP	W	16	1	TBD	A42	N / A for Pkg Type	
SN54HC595J	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	
SN74HC595D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DRG3	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
SN74HC595DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74HC595DWE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DWRE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595DWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595N	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74HC595NE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SN74HC595NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595NSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595NSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74HC595PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SNJ54HC595FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54HC595J	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	
SNJ54HC595W	OBSOLETE			16		TBD	Call TI	Call TI	

⁽¹⁾ The marketing status values are defined as follows:





vw.ti.com 29-Aug-2012

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN54HC595, SN54HC595-SP, SN74HC595:

Catalog: SN74HC595, SN54HC595

■ Enhanced Product: SN74HC595-EP, SN74HC595-EP

Military: SN54HC595

Space: SN54HC595-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications





29-Aug-2012

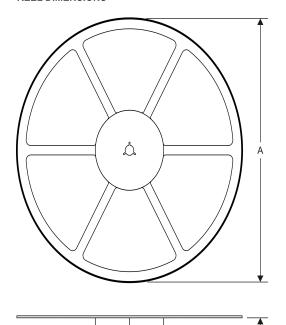
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

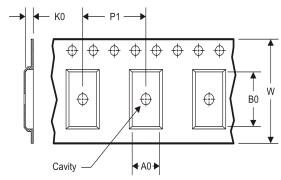
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



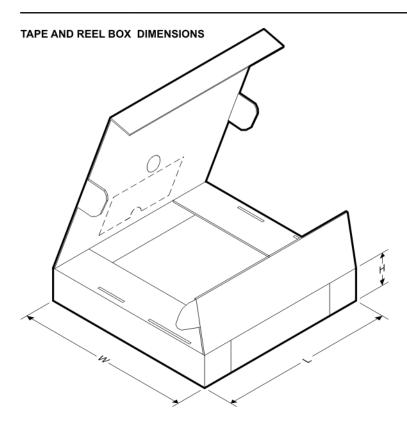
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package			SPQ	Reel	Reel Width	A0	B0	K0	P1	W	Pin1
	Туре	Drawing			Diameter (mm)	W1 (mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
SN74HC595DBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74HC595DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC595DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC595DRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC595DRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC595DWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
SN74HC595NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HC595PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC595DBR	SSOP	DB	16	2000	367.0	367.0	38.0
SN74HC595DR	SOIC	D	16	2500	367.0	367.0	38.0
SN74HC595DR	SOIC	D	16	2500	333.2	345.9	28.6
SN74HC595DRG4	SOIC	D	16	2500	333.2	345.9	28.6
SN74HC595DRG4	SOIC	D	16	2500	367.0	367.0	38.0
SN74HC595DWR	SOIC	DW	16	2000	366.0	364.0	50.0
SN74HC595NSR	SO	NS	16	2000	367.0	367.0	38.0
SN74HC595PWR	TSSOP	PW	16	2000	367.0	367.0	35.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F16 and JEDEC MO-092AC



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE

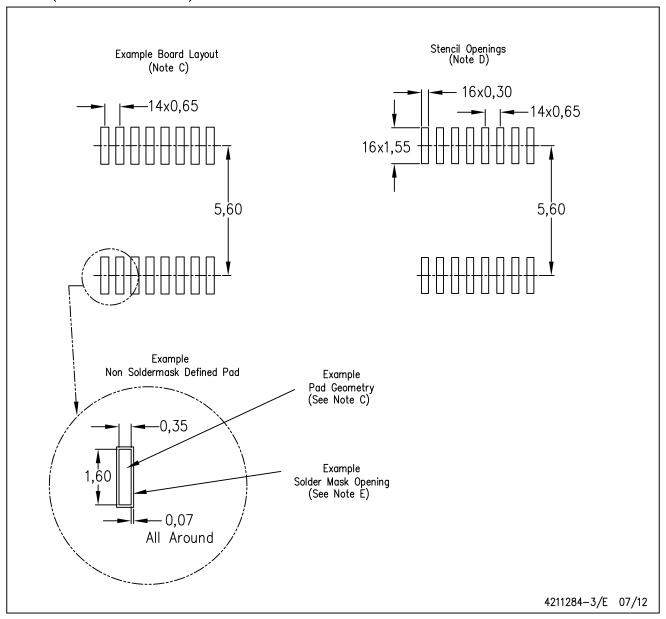


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



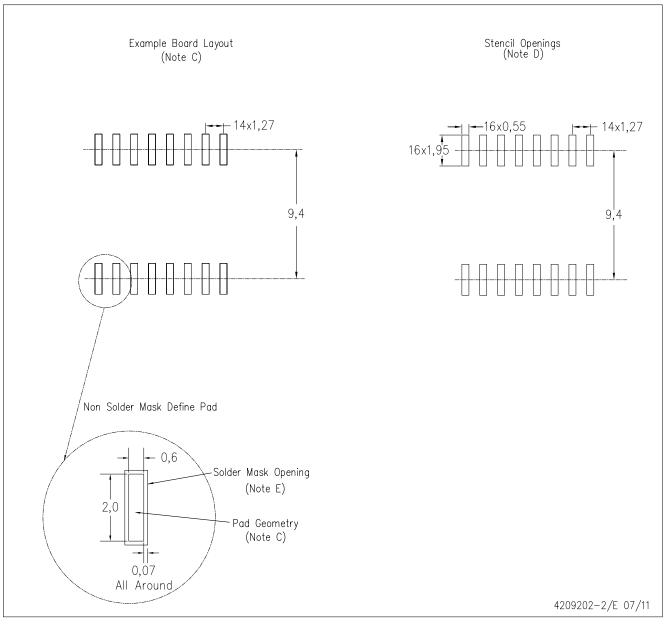
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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